RF and IF amplifiers with op amps

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Introduction
Why use op amps for RF design? Traditional RF design techniques using discrete transistors have been practiced successfully for decades. RF designers who are comfortable with things “as is” will scrutinize introduction of a new design technique using op amps. For high-performance RF equipment, however, high-speed op amps have some distinct advantages:

- When discrete transistors are used, the bias and operating points of the transistors interact with the gain and tuning of the stage. With op amps, the bias point is independent of gain and tuning.
- Op amp stages can operate over wide ranges of frequencies because there are no inductors to take into account.
- Transistor parameter drift and beta variation must also be taken into account over the system operating temperature range. When op amps are used, the drift is almost eliminated because gain is determined in stable passive components.

So what type of circuits can realistically be implemented with op amps? The remainder of this article describes wideband RF and narrow-band IF amplifiers.

Choosing the op amp
There is a decision to be made when selecting op amps for RF applications—whether to use voltage- or current-feedback amplifiers. Most analog interface designers are very familiar with voltage-feedback op amps but are needlessly apprehensive about current feedback. RF designers, being relatively new to op amps, probably have no such reservations. Voltage-feedback amplifiers, although a mature technology that is rapidly increasing in speed, still have a significant limitation of gain versus bandwidth imposed by their internal compensation capacitors. This limits their use in RF circuits to high-gain, relatively low-frequency circuits.

Current-feedback amplifiers are often pitched as having no limitation of gain versus bandwidth. Supposedly they are usable to almost their specified –3-dB frequency at just about any gain. This is only partially true. While there is no “~20 per decade” slope to their gain/bandwidth curve, they most definitely are bandwidth-limited at higher gains. Internal parasitics do take a toll on the bandwidth!

The stability of current-feedback amplifiers is determined solely by their feedback resistor value. This value, or narrow range of values, is often fairly low—a few hundred ohms at most. This makes the useful gain range fairly low—a voltage gain of 10 or 12 in a single stage.

Wideband RF amplifiers
For wideband RF amplifiers, current-feedback amplifiers are the components of choice. As an example, the THS3202 in Figure 1 was chosen for its wide bandwidth and fast slew rate. The circuit shown was used to produce an amplifier voltage gain of 20 and a stage voltage gain of 10.

Note the simplicity of this circuit compared to traditional RF circuitry. Provide the op amp, the termination and decoupling components, and two resistors—and the circuit is done! The 301-Ω (Rf) and 16.5-Ω (Rg) resistors are all that are required to set the stage gain. This circuit produces the amplitude curve in Figure 2.
The voltage gain of the op amp stage itself is 20, but this is cut in half by the action of the back termination resistor in combination with the load. The –3-dB point of the RF amplifier is about 390 MHz. If a flat gain over frequency is required, this circuit is only usable to about 200 MHz. Input and output VSWR values are better than 1.01:1 for most of the bandwidth, degrading to only about 1.1:1 near 200 MHz. $S_{12}$ is –75 dB over most of the bandwidth, degrading to only –50 dB near the bandwidth limit.

One might wonder if more gain could be coaxed from the stage by lowering the gain resistor ($R_G$) even more. The answer is yes, but there is a practical limit. Remember that the feedback resistor ($R_F$) is the determining factor for current-feedback amplifier stability. Remember also that $R_G$ has to drop proportionally more. One can see that it would not be long until the value of $R_G$ became impractically small. Lab tests were attempted with various values of $R_F$. The result was that there is no advantage to making it smaller than 200 $\Omega$. Below that, peeking starts to occur regardless of the value of $R_G$, becoming worse and worse as the resistance is made lower and lower. This is exactly what one would expect, because one thing to avoid in working with current-feedback amplifiers is to make $R_F$ a short.

More gain requires cascading multiple stages of THS3202 op amps. Fortunately for the designer, the THS3202 is a dual device, making a two-stage RF amplifier easy to implement at very little additional cost.

The circuit in Figure 3 shows such a cascaded RF amplifier, used to create a voltage gain of 100 (40 dB).

This circuit requires little explanation. It is obviously composed of two identical gain stages. Isolation is accomplished by using interstage termination resistors. The 39-pF capacitor provides peaking to compensate for some high-frequency roll-off, but better IP3 performance can be achieved by removing it and living with the roll-off. Overall circuit response is shown in Figure 4.

The reader will note that the stage is usable to 100 MHz, but there is significant peaking outside of that range. It is assumed that an amplifier of this high gain will be adequately shielded, and that there will be passive filtering components used to eliminate any problems from out-of-band response. Other S parameters for this circuit are similar to the case of the single op amp.

But what about voltage-feedback amplifiers? Is there any “niche” where they are more suitable than current-feedback amplifiers? There may be one. The stability of a voltage-feedback amplifier is primarily a function of its feedback and gain resistor ratio. Therefore, the designer is not constrained in the selection of a feedback resistor. Selecting a low-value feedback resistor can maximize the speed of the device; indeed, most data sheets recommend low feedback-resistor values. Making the resistor larger, however, does not adversely affect the stability of the
amplifier. This means that large resistor ratios are possible without making $R_G$ a very low value.

Figure 5 shows the response of a 40-dB RF amplifier constructed from a THS4271. Most notable is the bandwidth limitation; this amplifier is usable to only about 1 MHz. This might be valuable for medium-wave applications, but nothing higher in frequency. Yet the stage was constructed from a single op amp, with an $R_P$ of 10 kΩ and an $R_G$ of 49.9 Ω (that just happens to match the standard termination value). This gives a non-inverting gain of 201, but this gain is divided in two by the back termination resistor and the monitoring instrument. The freedom to use 10 kΩ as $R_P$ allows $R_G$ to be a reasonable value. Thus a single op amp is capable of delivering 40 dB of gain, something a current-feedback amplifier cannot do. As a test, a 455-kHz intermediate-frequency (IF) amplifier was constructed that had 37 dB of gain with a single op amp.

Therefore, there is a range of applications at relatively low frequencies and higher gains that are the exclusive domain of voltage-feedback amplifiers.

**Intermediate-frequency (IF) amplifiers**
The gain circuit shown in Figure 3 can easily be cascaded with ceramic filters and surface acoustic wave (SAW) filters to form high-performance IF stages. The only design consideration is the insertion loss of the filter, which may not be a constant value from part to part or from batch of parts to batch of parts, etc. If precise gain is needed from the stage, the designer may need to include a trim resistor in one or both stages. This trim adjustment, however, will not affect the tuning of the stage, except for a slight effect on its upper frequency limit.

**10.7-MHz IF amplifier**
There is widespread use of 10.7-MHz IF amplifiers in FM broadcast receivers and cell phone base station receivers (final IF). These products make use of inexpensive ceramic filters, which are available in a variety of bandwidths and insertion losses. The circuit shown in Figure 6 was constructed with the gain stage shown in Figure 3 and a 230-kHz bandwidth filter from Murata, the
SFELA10M7GA00-B0. This filter has a nominal insertion loss of 4 dB, and the circuit response is shown in Figure 7. The slight nonlinearity in the passband has more to do with the characteristics of the ceramic filter than it does with the op amp. Insertion loss is slightly more than 4 dB. This response has been corrected for the impedances of the circuit, which are different from a nominal load of 50 Ω. The response was actually measured with a 280-Ω resistor in series with the 50-Ω instrument as the load. That made a voltage divider, the effects of which have been compensated for in the figure.

**70-MHz IF amplifier**

Cellular telephone base stations and satellite communications receivers use 70-MHz IF amplifiers. At these frequencies, SAW filters are used. For our example, an 854660 filter from Sawtek was selected. This unit requires input and output inductors, and operates with standard 50-Ω input and output. Sawtek conveniently provided an EVM board, which greatly simplified prototyping. The circuit shown in Figure 8 produces the 70-MHz response shown in Figure 9.
The response curve in Figure 9 is almost identical in shape to the curve of the Sawtek filter itself. In other words, the amplifier is providing gain, while not adding undesirable harmonic content. The insertion loss of the SAW filter is about 7 dB.

**140-MHz IF amplifier**

Cellular telephone base stations also use 140-MHz IF amplifiers. For our example, an 854916 filter from Sawtek was selected along with smaller inductors, as shown in Figure 8. The circuit response is shown in Figure 10.

As was the case for the 70-MHz IF filter, the response curve in Figure 10 is almost identical in shape to the curve of the Sawtek filter itself. Again, the amplifier is providing gain, while not adding undesirable harmonic content. The insertion loss of the SAW filter is only 8 dB maximum; but the gain circuit itself is starting to roll off at this frequency, accounting for the rest of the loss. Careful examination of the passband shows the slight roll-off of the gain stage.

**Conclusion**

Although inexpensive RF design continues to be the exclusive domain of transistors, there is a class of RF applications where performance—not cost—is the driving factor. These applications stand to benefit tremendously from the excellent RF performance that op amps can provide. By freeing the designer from the interrelated tasks of calculating biasing and gain, decoupling, and peaking, op amps also simplify RF design, even for novices. Troublesome components such as inductors and variable peaking capacitors are eliminated, and circuit gain depends on relatively stable resistors instead of the widely variable parameters of transistors. This makes RF design with op amps repeatable in production and eliminates trimming and aligning test stations when the product is manufactured. Maintenance of the equipment, therefore, is also simplified; no periodic adjustments are needed to maintain top levels of performance.

**Related Web sites**

- [analog.ti.com](http://analog.ti.com)
- [www.ti.com/sc/device/THS3202](http://www.ti.com/sc/device/THS3202)
- [www.ti.com/sc/device/THS4271](http://www.ti.com/sc/device/THS4271)
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